2.5 V / 3.3 V, 622.08 MHz LVPECL Clock Oscillator

The single frequency, crystal oscillator (XO) is designed to meet today's requirements for 2.5 V / 3.3 V LVPECL clock generation applications. The device uses a high Q fundamental crystal and Phase Lock Loop (PLL) multiplier to provide 622.08 MHz, ultra low jitter and phase noise LVPECL differential output.

This device is a member of ON Semiconductor's PureEdge $^{\text{M}}$ clock family that provides accurate and precision clock solutions.

Frequency stability options available as either ± 50 PPM NBXSBA024 (Industrial Temperature Range) or ± 20 PPM NBXSBB024/NBXMBB024 (Commercial Temperature Range).

Available in 5 mm x 7 mm SMD (CLCC) package on 16 mm tape and reel in quantities of 1,000 and 100.

Features

- LVPECL Differential Output
- Uses High Q Fundamental Mode Crystal and PLL Multiplier
- Ultra Low Jitter and Phase Noise 0.5 ps (12 kHz 20 MHz)
- Output Frequency 622.08 MHz
- Hermetically Sealed Ceramic SMD Package
- RoHS Compliant
- Operating Range: 2.5 V $\pm 5\%$ or 3.3 V $\pm 10\%$
- Total Frequency Stability ±20 PPM; ±50 PPM
- This is a Pb–Free Device

Applications

- SONET Line Card
- Networking
- Optical Systems

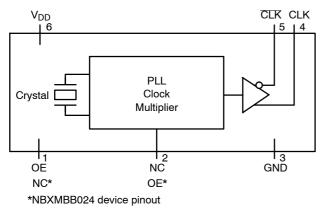


Figure 1. Simplified Logic Diagram



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6 PIN CLCC LN SUFFI) CASE 848A	
NBXSBx02 x	4 = Specific Device Code = A or B
У	= S or M NBXSB A 024 (±50 PPM) NBXSB B 024 (±20 PPM)
622.0800 AA WL YY WW	= Output Frequency (MHz) = Assembly Location = Wafer Lot = Year = Work Week
G	= Pb-Free Package

ORDERING INFORMATION

Device	Package	Shipping†
NBXSBA024LN1TAG	CLCC-6 (Pb-Free)	1000/ Tape & Reel
NBXSBB024LN1TAG*	CLCC-6 (Pb-Free)	1000/ Tape & Reel
NBXSBA024LNHTAG	CLCC-6 (Pb-Free)	100/ Tape & Reel
NBXMBB024LN1TAG	CLCC-6 (Pb-Free)	1000/ Tape & Reel
NBXMBB024LNHTAG	CLCC-6 (Pb-Free)	100/ Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

* Please contact sales office for availability

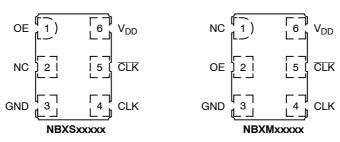


Figure 2. Pin Connections (Top View)

Table 1. PIN DESCRIPTION

Pin No.	Symbol	I/O	Description
1	OE/NC*	LVTTL/LVCMOS Control Input	Output Enable Pin. When left floating pin defaults to logic HIGH and output is active. See OE pin description Table 2.
2	NC/OE*	N/A	No Connect.
3	GND	Power Supply	Ground 0 V
4	CLK	LVPECL Output	Non–Inverted Clock Output. Typically loaded with 50 Ω receiver termination resistor to V_{TT} = V_{DD} – 2 V.
5	CLK	LVPECL Output	Inverted Clock Output. Typically loaded with 50 Ω receiver termination resistor to V_{TT} = V_{DD} – 2 V.
6	V _{DD}	Power Supply	Positive power supply voltage. Voltage should not exceed 2.5 V $\pm 5\%$ or 3.3 V $\pm 10\%.$

*NBXMBA024 device pinout

Table 2. OUTPUT ENABLE TRI-STATE FUNCTION

OE Pin	Output Pins
Open	Active
HIGH Level	Active
LOW Level	High Z

Table 3. ATTRIBUTES

Characteristic		Value
Internal Default State Resistor		170 kΩ
ESD Protection Human Body Model Machine Model		2 kV 200 V
Meets or Exceeds JE	DEC Standard EIA/JESD78	IC Latchup Test

1. For additional Moisture Sensitivity information, refer to Application Note AND8003/D.

Table 4. MAXIMUM RATINGS

Symbol	Parameter	Condition 1	Condition 2	Rating	Units
V _{DD}	Positive Power Supply	GND = 0 V		4.6	V
l _{out}	LVPECL Output Current	Continuous Surge		25 50	mA
T _A	Operating Temperature Range			-40 to +85	°C
T _{stg}	Storage Temperature Range			–55 to +120	°C
T _{sol}	Wave Solder	See Figure 5		260	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

Table 5. DC CHARACTERISTICS (V_{DD} = 2.5 V ± 5%; 3.3 V ± 10%, GM	$SND = 0 V, T_A = -40^{\circ}C \text{ to } +85^{\circ}C) \text{ (Note 2)}$
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Symbol	Characteristic		Conditions	Min.	Тур.	Max.	Units
I _{DD}	Power Supply Current				95	105	mA
V _{IH}	OE Input HIGH Voltage			2000		V _{DD}	mV
V _{IL}	OE Input LOW Voltage			GND – 300		800	mV
I _{IH}	Input HIGH Current	OE		-100		+100	μA
۱ _{IL}	Input LOW Current	OE		-100		+100	μA
V _{OH}	Output HIGH Voltage			V _{DD} -1195		V _{DD} -945	mV
V _{OL}	Output LOW Voltage			V _{DD} -1945		V _{DD} -1600	mV
V _{OUTPP}	Output Voltage Amplitude				700		mV

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfpm. Electrical parameters are guaranteed only over the declared operating temperature range. Functional operation of the device exceeding these conditions is not implied. Device specification limit values are applied individually under normal operating conditions and not valid simultaneously.

2. Measurement taken with outputs terminated with 50 Ω to V_DD – 2.0 V. See Figure 4.

Symbol	Characteristic	Conditions	Min.	Тур.	Max.	Units
f CLKOUT	Output Clock Frequency			622.08		MHz
Δf	Frequency Stability NBXSBB024, NBXMBB024 NBXSBA024	0°C to +70°C -40°C to +85°C (Note 4)			±20 ±50	ppm
Φ_{NOISE}	Phase-Noise Performance	100 Hz of Carrier		-88		dBc/Hz
	f _{CLKout} = 622.08 MHz (See Figure 3)	1 kHz of Carrier		-108		dBc/Hz
		10 kHz of Carrier		-115		dBc/Hz
		100 kHz of Carrier		-116		dBc/Hz
		1 MHz of Carrier		-122		dBc/Hz
		10 MHz of Carrier		-149		dBc/Hz
t _{jit} (Φ)	RMS Phase Jitter	12 kHz to 20 MHz		0.5	0.7	ps
t _{jitter}	Cycle to Cycle, RMS	1000 Cycles		1.5	8	ps
	Cycle to Cycle, Peak-to-Peak	1000 Cycles		15	30	ps
	Period, RMS	10,000 Cycles		1	4	ps
	Period, Peak-to-Peak	10,000 Cycles		10	20	ps
t _{OE/OD}	Output Enable/Disable Time				200	ns
t _{DUTY_CYCLE}	Output Clock Duty Cycle (Measured at Cross Point)		45	50	55	%
t _R	Output Rise Time (20% and 80%)			250	400	ps
t _F	Output Fall Time (80% and 20%)			250	400	ps
t _{start}	Start-up Time			1	5	ms
	Aging	1 st Year			3	ppm
		Every Year After 1 st			1	ppm

Table 6. AC CHARACTERISTICS (V_{DD} = 2.5 V \pm 5%; 3.3 V \pm 10%, GND = 0 V, T_A = -40°C to +85°C) (Note 3)

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfpm. Electrical parameters are guaranteed only over the declared operating temperature range. Functional operation of the device exceeding these conditions is not implied. Device specification limit values are applied individually under normal operating conditions and not valid simultaneously.

3. Measurement taken with outputs terminated with 50 Ω to V_DD – 2.0 V. See Figure 4.

4. Parameter guarantee 10 years aging. Includes initial stability at 25°C, shock, vibration, and first year aging.



Figure 3. Typical Phase Noise Plot

Parameter	Standard	Method
Shock	Mechanical	MIL-STD-833, Method 2002, Condition B
Solderability	Mechanical	MIL-STD-833, Method 2003
Vibration	Mechanical	MIL-STD-833, Method 2007, Condition A
Solvent Resistance	Mechanical	MIL-STD-202, Method 215
Thermal Shock	Environment	MIL-STD-833, Method 1011, Condition A
Moisture Level Sensitivity	Environment	MSL1 260°C per IPC/JEDEC J-STD-020D

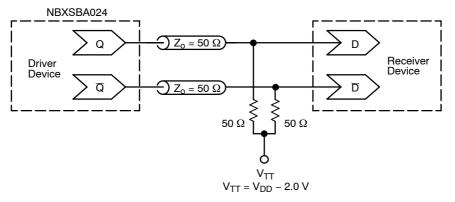


Figure 4. Typical Termination for Output Driver and Device Evaluation (See Application Note AND8020/D – Termination of ECL Logic Devices.)

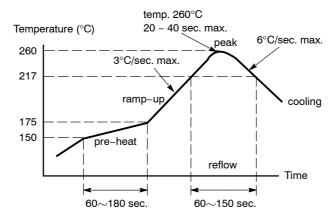
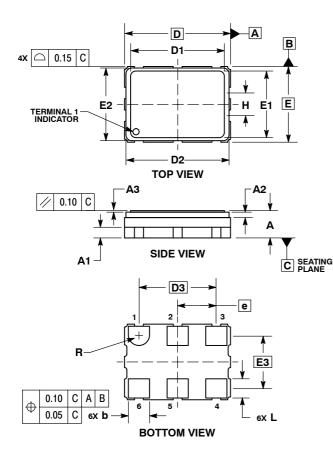


Figure 5. Recommended Reflow Soldering Profile

PACKAGE DIMENSIONS

6 PIN CLCC, 7x5, 2.54P CASE 848AB-01 ISSUE C



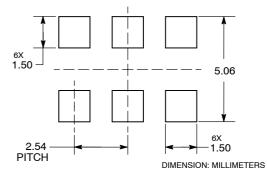
NOTES:

1. DIMENSIONING AND TOLERANCING PER ASME Y14 5M 1994

ASME Y14.5M, 1994. 2. CONTROLLING DIMENSION: MILLIMETERS.

	MILLIMETERS			
DIM	MIN	NOM	MAX	
Α	1.70	1.80	1.90	
A1		0.70 REF		
A2		0.36 REF		
A3	0.08	0.10	0.12	
b	1.30	1.40	1.50	
D	7.00 BSC			
D1	6.17	6.20	6.23	
D2	6.66	6.81	6.96	
D3	5.08 BSC			
E		5.00 BSC		
E1	4.37	4.40	4.43	
E2	4.65	4.80	4.95	
E3		3.49 BSC		
е	2.54 BSC			
н	1.80 REF			
L	1.17	1.27	1.37	
R		0.70 REF		

SOLDERING FOOTPRINT*



*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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